

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

FMV20N60S1

FEATURES

- · Low on-resistance:
 - $R_{DS}(on) \le 0.19\Omega \pmod{2}$
- Low switching loss
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

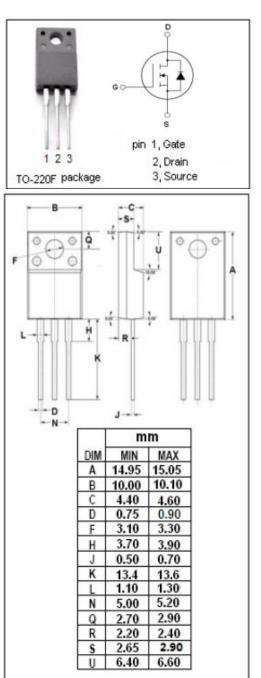
- UPS (Uninterruptible Power Supply)
- Power conditioner system
- Power supply

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	600	V	
V _{GS}	Gate-Source Voltage	±30	V	
ID	Drain Current-Continuous	20	А	
I _{DM}	Drain Current-Single Pulsed	60	А	
PD	Total Dissipation @Tc=25°C		W	
Tj	Max. Operating Junction Temperature 150		°C	
T _{stg}	Storage Temperature	-55~150	°C	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	2.36	°C /W	
Rth(ch-a)	Channel-to-ambient thermal resistance	58	°C/W	





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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	600			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =0.25mA	2.5		3.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =10A			0.19	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±100	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =600V; V _{GS} = 0V			25	μA
V _{SD}	Diode forward voltage	I _{DR} =20A, V _{GS} = 0 V			1.35	V

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